

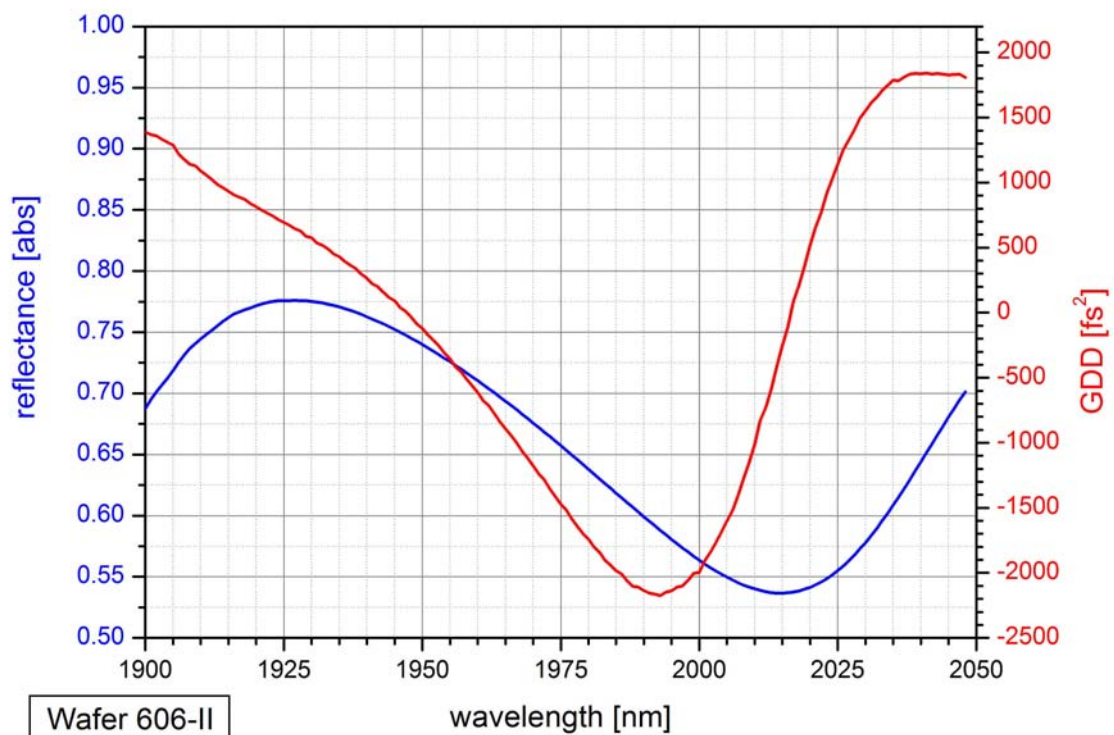
SAM™ Data Sheet SAM-1960-30-10ps-x, $\lambda = 1960$ nm

Laser wavelength	$\lambda = 1960$ nm
High reflection band (R > 55%)	$\lambda = 1900 \dots 2080$ nm
Absorbance	$A_0 = 30$ %
Modulation depth	$\Delta R = 18$ %
Non-saturable loss	$A_{ns} = 12$ %
Saturation fluence	$\Phi_{sat} = 65 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 10$ ps
Damage threshold	$\Phi = 1$ mJ/cm ²
Chip area	4 mm x 4 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion



Wafer 606-II

